L	Туре		# Hit	s Search Text	DBs
1	IS&R	Ь7	1603	(327/108).CCLS.	US-PGPUB; USPAT
2	BRS	L8	700	7 and (comparator amplifier) and transistor	
3	BRS	L9	677	327/112.ccls.	US-PGPUB; USPAT
4	BRS	L10	298	<pre>9 and (comparator amplifier) and transistor</pre>	
5	BRS	L11	217	10 not 8	US-PGPUB; USPAT
6	IS&R	L12	162	(327/323).CCLS.	US-PGPUB; USPAT
7_	IS&R	L13	177	(327/404).CCLS.	US-PGPUB; USPAT
8	BRS	L14	2058	transistor.ti. and (comparator amplifier)	USOCR; EPO; JPO DERWENT; IBM_TDE
9	BRS	L15	2902	14 and sens\$3	USOCR; EPO; JPO; DERWENT; IBM_TDE
10		L16	1103	15 and (resistor diode)	USOCR; EPO; JPO; DERWENT; IBM_TDB
11	IS&R	L17	531	(361/93.1).CCLS.	US-PGPUB; USPAT
12	BRS	L18	164	17 and (comparator amplifier) and transistor	US-PGPUB; USPAT
13	BRS	L19	3662	current near2 protect\$3.ti.	USOCR; EPO; JPO; DERWENT; IBM_TDB
4	BRS	L20	547	19 and (amplifier comparator)	USOCR; EPO; JPO; DERWENT; IBM_TDB
.5	IS&R	L22	322	(361/93.9) . CCLS.	US-PGPUB; USPAT
.6	BRS	L25	3664	current near2 protect\$5.ti.	USOCR; EPO; JPO; DERWENT; IBM_TDB
.7	BRS	L26	606	25 and transistor	USOCR; EPO; JPO; DERWENT; IBM_TDB
8	BRS	L27	3010	overcurrent near2 protect\$5.ti.	USOCR; EPO; JPO; DERWENT; IBM_TDB
9	BRS	L28	739	27 and transistor	USOCR; EPO; JPO; DERWENT; IBM_TDB
0		L29	21790	transistor same (amplifier comparator) same (sens\$3 detect\$3) same (resistor diode)	US-PGPUB; USPAT
		L30	1139	29.clm.	US-PGPUB; USPAT
		L31	600	10.0	US-PGPUB; USPAT
.		L34	762	1/305/105	US-PGPUB; USPAT
<u> </u>	BRS	L35	402	12.4 2 2 2 2	US-PGPUB; USPAT